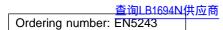
### 捷多邦,专业PCB打样工厂,24小时加急出货



### Monolithic Digital IC

-20 to +100

-55 to +120

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### **LB1694N**

# 3-phase Brushless Motor Driver

# **Overview**

The LB1694N is a 3-phase brushless motor driver IC that is ideal for driving DC fan motors in air conditioners, hot-water WWW.DZSC.COM supply systems, and the like.

W.DZSG.CO

# **Features**

- 3-phase brushless motor driver.
- Withstand voltage: 45 V; output current: 2.5 A.
- Current limiter built in.
- · Low-voltage protector circuit built in.
- Thermal shutdown protector built in.
- Hall amplifier with hysteresis built in.
- FG output function.

Operating temperature

Storage temperature

# Specif

### Absolut

Absolute Maximum Ratings at Ta = 25 °C							
Maximum supply voltage	V <sub>CC</sub> max		10	V			
	V <sub>M</sub> max	ANA LEL	45	V			
Output current	lo		2.5	A			
Allowable power dissipation	Pd max1	Independent IC	2.2	W			
	Pd max2	With arbitrarily large heat sink	15.2	W			

### Allowable Operating Ranges at Ta = 25 °C

Parameter	Symbol	Conditions	Ratings	Unit
	V <sub>CC</sub>		4.5 to 5.5	V
Supply voltage range	V <sub>M</sub>		5 to 42	V
Power supply veltage rise rate	$\Delta V_{CC} / \Delta t$	V <sub>CC</sub> = V <sub>LVSD</sub> (OFF) point *1	to 0.04	V/µs
Power supply voltage rise rate	ΔV <sub>M</sub> / Δt	$V_{M} = 0 V \text{ point*1}$	to 0.16	V/µs

\*1 If the supply voltage rise rate is fast when power is applied, through current may flow to output.

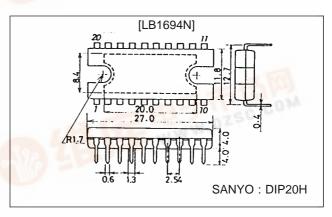
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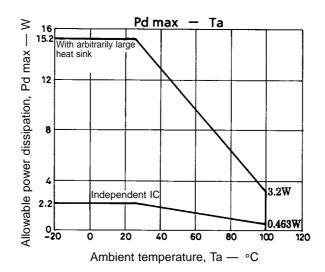
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# SANYO Electric Co.,Ltd. Semiconductor Bussiness Headquarters TOKYO OFFICE Tokyo Bldg., 1-10, 1 Chome, Ueno, Taito-ku, TOKYO, 110 JAPAN

# Package Dimensions unit : mm

### 3037A-DIP20H





# Electric Characteristics at Ta = 25 $^{\circ}C,$ $V_{CC}$ = 5 V, $V_{M}$ = 30 V

Parameter	Symbol	Conditions	min	typ	max	Unit
Supply current	Icc	Forward		13	19	mA
	V <sub>Osat1</sub>	$I_0 = 1 \text{ A}, V_0 \text{ (sink)} + V_0 \text{ (source)}$		2.1	3.0	V
Output saturation voltage	V <sub>Osat2</sub>	$I_0 = 2 \text{ A}, V_0 \text{ (sink)} + V_0 \text{ (source)}$		3.0	4.2	V
Output leak current	I <sub>O(leak)</sub>				100	μA
Hall amplifier						
Input bias current	I <sub>HB</sub>			1	4	μA
Common-mode input voltage range	V <sub>ICM</sub>		1.5		3.2	V
Hysteresis width	ΔV <sub>IN</sub>		21	30	37	mV
Input voltage L $\rightarrow$ H	V <sub>SLH</sub>		5	15	25	mV
Input voltage $H \rightarrow L$	V <sub>SHL</sub>		-25	-15	-5	mV
FG pin (rate pulse output)						
Low level output voltage	V <sub>FGL</sub>	I <sub>FG</sub> = 5 mA			0.4	V
Pull-up resistance	R <sub>FG</sub>		7.5	10	12.5	kΩ
F/R operation Forward	V <sub>FR1</sub>			0	0.8	V
F/R operation Reverse	V <sub>FR2</sub>		4.2	5.0		V
Current limit operation limiter	V <sub>RF</sub>		0.42	0.5	0.6	V
Thermal shutdown operation temperature	T <sub>SD</sub>	Design target	120	150		۰C
Hysteresis width	ΔT <sub>SD</sub>	Design target		30		°C
Reduced voltage protection operation voltage	V <sub>LVSD</sub>		3.5	3.8	4.1	V
Reduced voltage protection release voltage	V <sub>LVSD(OFF)</sub>			4.3	4.5	V
Hysteresis width	$\Delta V_{LVSD}$		0.4	0.5	0.6	V
C pin charge current	ICL	R = 33 kΩ	30	40	50	μA
C pin discharge current	Існ	R = 33 kΩ	90	120	150	μA
C pin charge start voltage	V <sub>CL</sub>	R = 33 kΩ	0.3	0.4	0.5	V
C pin discharge start voltage	V <sub>CH</sub>	R = 33 kΩ	1.5	2.0	2.5	V
Output current neglect time	t <sub>sm</sub>	R = 33 kΩ, C = 4700 pF	58	68	78	μs
Output off time	t <sub>so</sub>	R = 33 kΩ, C = 4700 pF	164	193	222	μs

# **Truth Table**

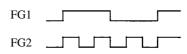
	Input		F/R control	/R control Output		FG output					
	IN1	IN2	IN3	F/R	Source $\rightarrow$ Sink	FG1	FG2				
1 H L	ц	1	н	L	$OUT2 \rightarrow OUT1$	_ L					
			Н	$OUT1 \rightarrow OUT2$		L					
2	н		1	L	$OUT3 \rightarrow OUT1$	– L	н				
Z			L	Н	$OUT1 \rightarrow OUT3$						
3	нн	н		L	$OUT3 \rightarrow OUT2$	I	L				
3			L L	Н	$OUT2 \rightarrow OUT3$						
		1	L	$OUT1 \rightarrow OUT2$	н						
4		Н		Н	П			Н	$OUT2 \rightarrow OUT1$		Н
5 L	L Н Н		L	$OUT1 \rightarrow OUT3$	н						
		Н	$OUT3 \rightarrow OUT1$								
6 L		L L H		L	$OUT2 \rightarrow OUT3$		н				
				н	$OUT3 \rightarrow OUT2$	– Н					

F/R

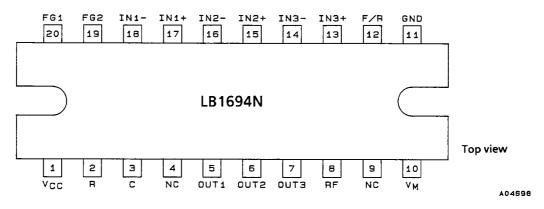
 Forward
 L
 0.0 to 0.8 V

 Reverse
 H
 4.2 to 5.0 V





# Pin Assignment



Current

Limiter

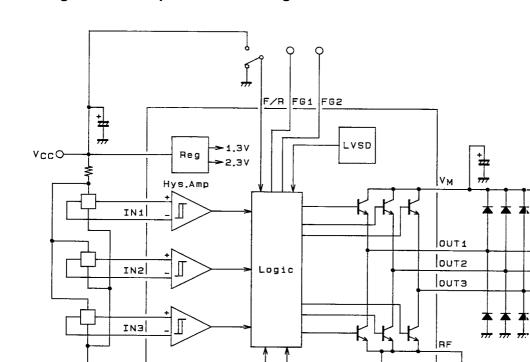
С

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R

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0.5V



TSD

GND

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## **Pin Functions**

Pin No.	Pin Name	Pin Voltage	Equivalent Circuit Diagram	Pin Function		
1	V <sub>CC</sub>			Supplies power to all circuits except outpu block.		
2	R			Sets the C pin charge/discharge current.		
3	С			Sets the output off time and output curren neglect time during current limiter operation.		
5 6 7	OUT1 OUT2 OUT3			Output pin 1 Output pin 2 Output pin 3		
8	RF	-		Output current detection pin. By inserting resistor $R_f$ between this pin and GND, the output current is detected as voltage. The output current is limited to a current value se by $V_{RF}/R_f$ (current limit operation).		
10	V <sub>M</sub>	-	404701	Power supply pin providing output.		
11	GND			GND for other than output. The minimum potential of output transistor is the RF pin voltage.		
12	F/R	0.0 V min V <sub>CC</sub> max		Forward/reverse control pin.		
17, 18, 15, 16, 13, 14	IN1 <sup>+</sup> , IN1 <sup>-</sup> IN2 <sup>+</sup> , IN2 <sup>-</sup> IN3 <sup>+</sup> , IN3 <sup>-</sup>	1.5 V min V <sub>CC</sub> -1.8 V max		Hall device input pin. Logic "H" represents IN⁺ > IN⁻.		
19	FG2		VCC	Rate pulse output pin 2.		
20	FG1			Pull-up resistor built in. Rate pulse output pin 1. Pull-up resistor built in.		

1. Hall input circuit

The Hall input circuit is a differential amplifier with hysteresis (30 mV typ). The operating DC level must be within the common-mode input voltage range (1.5 V to  $V_{CC} - 1.8$  V). An input level that is at least three times greater than the hysteresis (from 120 to 160 mVp-p) is recommended to be independent of noise, etc. If the handling capability needs to be considered in noise evaluation, etc., connect a capacitor (about 0.01  $\mu$ F) between the Hall inputs IN<sup>+</sup> and IN<sup>-</sup>.

#### 2. Protectors

### 2-1. Reduced voltage protector

If  $V_{CC}$  drops below the prescribed voltage ( $V_{LVSD}$ ), the output transistor on the sink side turns off. This protector prevents malfunction which may occur when  $V_{CC}$  is reduced.

2-2. Thermal shutdown protector

If the junction temperature exceeds the prescribed temperature  $(T_{SD})$ , the output transistor on the sink side turns off. This protector prevents the IC from being damaged by heat. Thermal design must be such that no operation is performed in other modes than abnormality.

3. FG output circuit

IN1, IN2, and IN3 Hall input signals are composited and wave shaped to be output. FG1 has the same frequency as for Hall input, while FG2 3-fold as many.

4. Forward/reverse controller

No forward/reverse (F/R) switching is assumed to be performed during motor running period. If F/R switching is performed during motor running period, through current flows to output and ASO needs to be considered. It is recommended that F/R switching be performed when the  $V_M$  power supply is off (in motor stop mode).

5. V<sub>CC</sub> and V<sub>M</sub> power supplies

If the supply voltage  $(V_{CC}, V_M)$  rise rate is fast when power is applied, through current flows to output and ASO needs to be considered. The supply voltage rise rate must be such that  $\Delta V_{CC}/\Delta t = 0.04 \text{ V/}\mu \text{s}$  or less and  $\Delta V_M/\Delta t = 0.16 \text{ V/}\mu \text{s}$  or less. The desirable order of applying power is  $V_{CC}$  on first and then  $V_M$  on. The desirable order of turning off power supply is  $V_M$  off first and then  $V_{CC}$  off after motor stop. If, after  $V_M$  is turned off,  $V_{CC}$  is turned off during motor's inertial running, some types of motors have a possibility that  $V_M$  voltage rises, exceeding the withstand voltage.

6. Power supply stabilization capacitor

Great fluctuations in the  $V_{CC}$  line may cause the reduced-voltage protector, etc. to malfunction. A capacitor (several  $\mu$ F) needs to be connected to the  $V_{CC}$  line (between  $V_{CC}$  and GND) for stabilization. Since a large switching current flows in the  $V_M$  line, wiring inductance component, etc. fluctuates. Because there are also fluctuations in the GND line, a capacitor needs to be connected to the  $V_M$  line (between  $V_M$  and GND) for stabilization thus preventing malfunction and keeping the withstand voltage from being exceeded. Especially when the routing of wiring ( $V_M$ ,  $V_{CC}$ , or GND) is long, be sure to connect capacitors with adequate capacity for power line stabilization.

7. Current limiter

The current limiter turns off the sink side output transistor when the output current-set current value (limiter value) is reached. The output current is limited by the limit value. The RF pin is used to detect the output current. The output current is detected as voltage by connecting resistor  $R_f$  between RF pin and GND. When the RF pin voltage reaches 0.5 V (typ), the current limiter operates so that the output current is limited to the 0.5/ $R_f$ -set limiter value.

7-1. Output off time

The current limiter is so designed that current limit function turns on to turn off the sink side output transistor and then turn on the transistor again after off period of a fixed time (output off time) has elapsed. Since the LB1694N uses this output switching method for the current limiter, it is hardly necessary to consider ASO in current limiter operated mode as compared with the output unsaturated current limited one. The output off time depends on charge time of capacitor C connected to the C pin. When the current limiter turns on, C begins charging and the output is kept off until C is charged up to 2 V (typ). When C has been charged up to 2 V, the sink side output turns on again. The C charging current is a constant-regulated current which depends on resistor R connected to the R pin. The C charging current  $I_{CL}$  and output off time  $t_{off}$  are calculated as follows:

$$\begin{split} I_{CL} &= 1.3/R \text{ (R must be set to be 13 k}\Omega \text{ and 100 k}\Omega.) \\ t_{off} &= C/I_{CL} \times 2.0 \\ &= 1.53 \times R \times C \end{split}$$

7-2. Output current neglect time

While the current limiter turns on and the sink side output is off, the regeneration current flows through the external diode used for absorbing the regeneration current above the output that was turned off. After the output off time elapses and the sink side output is turned on again, reverse current flows momentarily through the external diode (for the diode's reverse recovery time), causing the current that reaches the limiter value to flow momentarily through the output. Because this current will cause current limiter to turn on again, turning off the output, the average current decreases, causing the torque to be decreased at motor start-up, etc. Therefore, in order to prevent this current from being detected, the current limiter is designed so that the output current is not detected for a fixed period of time after the sink side output is turned on again. This length of time is the output current neglect time. The output current neglect time is determined by the discharge time of the capacitor C connected to the C pin. When current limiter turns on and C charges to 2 V, C begins discharging, and the output current neglect time is the time it takes for C to discharge to the point where the voltage at C is 0.4 V (typ). The C discharge current is a constant current, and is set at about 3 times charge current I<sub>CL</sub>. As a result, the output current neglect time is about 1/3 of the output off time. The C discharge current I<sub>CH</sub> and the output current neglect time t<sub>sm</sub> are determined according to the following equations:

$$\begin{array}{l} I_{CL} \doteq 1.3/R \times 3 \\ t_{sm} \doteq C/I_{CL} \times 1.6 \\ \doteq 0.41 \times R \times C \end{array}$$

Because there is a slope to the time at which the sink side output is turned on again, the reverse current is not very large, even if a rectifier diode (a diode in which the reverse recovery time is not short) is used as the external diode for absorbing the regeneration current in the current limiter.

### 7-3. Output off time setting

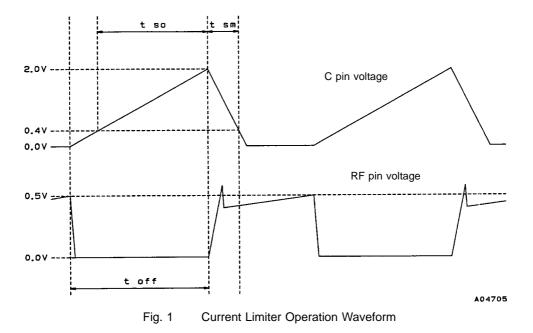
It is necessary to set the output off time to a suitable level for the type of motor being used. (The output off time is set by the external resistors connected to the R pin, and by the external capacitor connected to the C pin.) Fig. 1 shows the current limiter operation waveform.

(1) When the output off time is set short

The output current neglect time is set by a circuit within the IC to about 1/3 of the output off time. Therefore, if the output off time is set to a very short length of time, the output current neglect time may not be adequate. If the output current neglect time is inadequate, the current limiter will turn on in response to reverse current from the external diode used to absorb the regeneration current. (Refer to Section 7-2.) Furthermore, if the output off time is short, the diode reverse current becomes large and ASO must be considered.

(2) When the output off time is set long

If the output off time is set to a very long length of time, the average current decreases, with the result that the torque at motor start-up drops. Depending on the type of motor, it may be impossible to shift from the current limiter operation state to the normal rotation state.



- 8. Calculation of the IC's internal power dissipation  $Pd = (V_{CC} \times I_{CC}) + (V_M \times I_M) - (power dissipated by the motor coil)$
- Measuring the increase in the IC's temperature Because the temperature of the IC chip cannot be measured directly, the temperature is normally measured using one of the following methods.
- 9-1. Measurement using a thermocouple In order to measure the temperature by using a thermocouple, mount the thermocouple on the fin. Although this method of measurement is simple, if the rate of heat generation has not stabilized, the measurement error is great.
- 9-2. Measurement using the characteristics of a diode within the IC It is recommended that the parasitic diode between FG1 and GND be used to measure the temperature of the IC. Set FG1 high (the "off" state), measure the parasitic diode voltage  $V_F$ , and calculate the temperature based on the temperature characteristics of the voltage  $V_F$ . (Sanyo's data:  $I_F = -1$  mA,  $V_F$  temperature characteristics: approximately -2 mV/ °C)
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